NSN 5961-00-246-8945

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal
Overall Length:
Between 0.330 inches and 0.505 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.544 inches and 0.562 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 breakover voltage, dc
Current Rating Per Characteristic:
35.00 amperes source cutoff current of standard range
Power Rating Per Characteristic:
12.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Filg:

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